



## CERTIFICATE

No. Z2 120422 0001 Rev. 01

Holder of Certificate: Qn-SOLAR PV LIMITED

Unit 2 of LG 1, Mirror Tower, 61 Mody Road

999077 Tsim Sha Tsui, Kowloon

HONG KONG

**Certification Mark:** 



Product: Crystalline Silicon Terrestrial Photovoltaic

(PV) Modules

Mono-crystalline Silicon Photovoltaic (PV)

**Modules** 

The product was tested on a voluntary basis and complies with the essential requirements. The certification mark shown above can be affixed on the product. It is not permitted to alter the certification mark in any way. In addition, the certification holder must not transfer the certificate to third parties. This certificate is valid until the listed date, unless it is cancelled earlier. All applicable requirements of the testing and certification regulations of TÜV SÜD Group have to be complied. For details see: www.tuvsud.com/ps-cert

**Test report no.:** 882162307102

**Valid until:** 2028-02-26

**Date**, 2023-06-26

( Xinlian LUO )



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Model(s):

With  $\frac{1}{2}$  cut of 210 mono c-Si cell (132pcs): QNM210-HGxxx-66 (xxx=645-670, in step of 5) With  $\frac{1}{2}$  cut of 210 mono c-Si cell (120pcs): QNM210-HGxxx-60(xxx=590-610, in step of 5) With  $\frac{1}{2}$  cut of 210 mono c-Si cell (110pcs): QNM210-HGxxx-55 (xxx=540-560, in step of 5) With \( \frac{1}{3} \) cut of 210 mono c-Si cell (150pcs): QNM210-HGxxx-50 (xxx=490-510, in step of 5) With  $\frac{1}{2}$  cut of 182 mono c-Si cell (144pcs): QNM182-HGxxx-72 (xxx=530-555, in step of 5) With  $\frac{1}{2}$  cut of 182 mono c-Si cell (132pcs): QNM182-HGxxx-66 (xxx=480-500, in step of 5) With  $\frac{1}{2}$  cut of 182 mono c-Si cell (120pcs): QNM182-HGxxx-60 (xxx=440-460, in step of 5) With  $\frac{1}{2}$  cut of 182 mono c-Si cell (108pcs): QNM182-HGxxx-54 (xxx=395-415, in step of 5) With  $\frac{1}{2}$  cut of 210 mono c-Si cell (132pcs): QNN210-HGxxx-66 (xxx=670-695, in step of 5) With ½ cut of 210 mono c-Si cell (120pcs): QNN210-HGxxx-60 (xxx=610-630, in step of 5) With  $\frac{1}{2}$  cut of 210 mono c-Si cell (110pcs): QNN210-HGxxx-55 (xxx=555-575, in step of 5) With ½ cut of 182 mono c-Si cell (144pcs): QNN182-HGxxx-72 (xxx=555-575, in step of 5) With ½ cut of 182 mono c-Si cell (120pcs): QNN182-HGxxx-60(xxx=465-475, in step of 5) With  $\frac{1}{2}$  cut of 182 mono c-Si cell (108pcs): QNN182-HGxxx-54 (xxx=415-430, in step of 5) xxx is standing for rated output power at STC

#### **Parameters:**

Safety Class: Class II

Max. System Voltage: 1500 V DC

Fire Safety Class: Class C according to UL790.

Test Laboratory: Metrology and Testing Center of China Electronics Technology Group Corporation

No.18th Research Institute

(NO.6 Huake seven RD, Haitai street, Xiging District, Tianjin, 300384, China)

Construction: Framed, with Junction box, Cable and Connector.

#### Production Facilities:

1. Jiangsu Zhongqing Photovoltaic Technology Co., Ltd.

26, North Side of Taishan Road, Xiyi High-tech Zone, Xinyi City

Production Facility Number: 119915

ZhongQing Intelligence Industrial (HuBei) Co.,LTD.

Shuanglian Industrial Park, Dangyang Economic Development Zone, Hu-bei Province

Production Facility Number: 120038



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Tested IEC 61215-1:2016 IEC 61215-1-1:2016 IEC 61215-1-2016 IEC 61215-2:2016

IEC 61730-1:2016 IEC 61730-2:2016 EN 61215-1:2016 EN 61215-1-1:2016 EN 61215-2:2017 EN IEC 61730-1:2018 EN IEC 61730-2:2018

EN IEC 61730-1:2018/AC:2018-06 EN IEC 61730-2:2018/AC:2018-06